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74LCX16245 Low Voltage 16-Bit Bidirectional Transceiver with 5V Tolerant Inputs and Outputs

General Description

The LCX16245 contains sixteen non-inverting bidirectional buffers with 3-STATE outputs and is intended for bus oriented applications. The device is designed for low voltage (2.5V or 3.3V) V_{CC} applications with capability of interfacing to a 5V signal environment. The device is byte controlled. Each byte has separate control inputs which could be shorted together for full 16-bit operation. The T/R inputs determine the direction of data flow through the device. The OE inputs disable both the A and B ports by placing them in a high impedance state.

The LCX16245 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining CMOS low power dissipation.

Features

- 5V tolerant inputs and outputs
- 2.3V–3.6V V_{CC} specifications provided
- \blacksquare 4.5 ns t_{PD} max (V_{CC} = 3.3V), 20 μA I_{CC} max
- Power down high impedance inputs and outputs

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- Supports live insertion/withdrawal (Note 1)
- \blacksquare ±24 mA output drive (V_{CC} = 3.0V)
- Uses patented noise/EMI reduction circuitry
- Latch-up performance exceeds 500 mA
- ESD performance: Human body model > 2000V
 - Machine model > 200V
- Also packaged in plastic Fine-Pitch Ball Grid Array (FBGA)

Note 1: To ensure the high-impedance state during power up or down, OE should be tied to V_{CC} through a pull-up resistor: the minimum value or the resistor is determined by the current-sourcing capability of the driver.

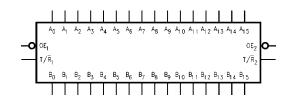
Ordering Code:

Order Number	Package Number	Package Description
74LCX16245G (Note 2)(Note 3)	BGA54A	54-Ball Fine-Pitch Ball Grid Array (FBGA), JEDEC MO-205, 5.5mm Wide
74LCX16245MEA (Note 3)	MS48A	48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
74LCX16245MTD (Note 3)	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Note 2: Ordering code "G" indicates Trays.

Note 3: Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code

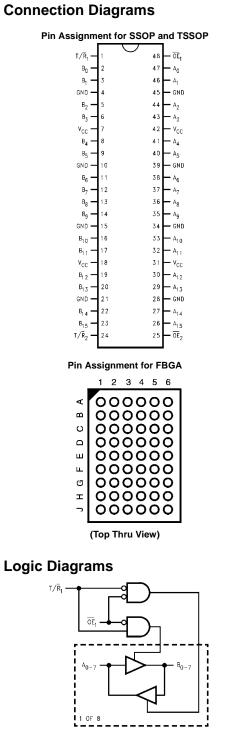
Logic Symbol



'4LCX16245 Low Voltage 16-Bit Bidirectional Transceiver with 5V Tolerant Inputs and Outputs

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74LCX16245



Pin Descriptions

Pin Names	Description
OEn	Output Enable Input
T/R _n	Transmit/Receive Input
$A_0 - A_{15}$ $B_0 - B_{15}$ NC	Side A Inputs or 3-STATE Outputs
B ₀ -B ₁₅	Side B Inputs or 3-STATE Outputs
NC	No Connect

FBGA Pin Assignments

	1	2	3	4	5	6
Α	B ₀	NC	T/R ₁	OE ₁	NC	A ₀
В	B ₂	B ₁	NC	NC	A ₁	A ₂
С	B ₄	B ₃	V _{CC}	V _{CC}	A ₃	A ₄
D	B ₆	B ₅	GND	GND	A ₅	A ₆
E	B ₈	B ₇	GND	GND	A ₇	A ₈
F	B ₁₀	B ₉	GND	GND	A ₉	A ₁₀
G	B ₁₂	B ₁₁	V _{CC}	V _{CC}	A ₁₁	A ₁₂
Н	B ₁₄	B ₁₃	NC	NC	A ₁₃	A ₁₄
J	B ₁₅	NC	T/R_2	OE ₂	NC	A ₁₅

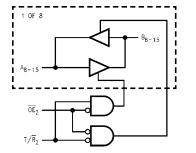
Truth Tables

Inp	outs	Outrasta		
OE ₁	T/R ₁	Outputs		
L	L	Bus B ₀ –B ₇ Data to Bus A ₀ –A ₇		
L	н	Bus B_0-B_7 Data to Bus A_0-A_7 Bus A_0-A_7 Data to Bus B_0-B_7		
Н	х	HIGH Z State on A ₀ -A ₇ , B ₀ -B ₇		

Inp	outs	Outrasta
OE ₂	T/R ₂	Outputs
L	L	Bus B ₈ –B ₁₅ Data to Bus A ₈ –A ₁₅
L	н	Bus A ₈ -A ₁₅ Data to Bus B ₈ -B ₁₅
Н	Х	HIGH Z State on A8-A15, B8-B15

H = HIGH Voltage Level L = LOW Voltage Level

X = Immaterial Z = High Impedance



Note: Please note that these diagrams are provided only for the understanding of logic operations and should not be used to estimate propagation delays.

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Symbol	Parameter	Value	Conditions	Units	
V _{CC}	Supply Voltage	-0.5 to +7.0		V	
VI	DC Input Voltage	-0.5 to +7.0		V	
Vo	DC Output Voltage	-0.5 to +7.0	Output in 3-STATE	V	
		–0.5 to V _{CC} + 0.5	Output in HIGH or LOW State (Note 5)	v	
I _{IK}	DC Input Diode Current	-50	V _I < GND	mA	
ок	DC Output Diode Current	-50	V _O < GND	m /	
		+50	$V_{O} > V_{CC}$	mA	
I _O	DC Output Source/Sink Current	±50		mA	
I _{CC}	DC Supply Current per Supply Pin	±100		mA	
GND	DC Ground Current per Ground Pin	±100		mA	
T _{STG}	Storage Temperature	-65 to +150		°C	

Recommended Operating Conditions (Note 6)

Symbol	Parameter		Min	Max	Units
V _{CC}	Supply Voltage	2.0	3.6	V	
		Data Retention	1.5	3.6	v
VI	Input Voltage		0	5.5	V
Vo	Output Voltage	HIGH or LOW State	0	V _{CC}	V
		3-STATE	0	5.5	v
I _{OH} /I _{OL}	Output Current	V _{CC} = 3.0V – 3.6V		±24	
		$V_{CC} = 2.7V - 3.0V$ $V_{CC} = 2.3V - 2.7V$		±12	mA
		$V_{CC} = 2.3V - 2.7V$		±8	
T _A	Free-Air Operating Temperature		-40	85	°C
$\Delta t / \Delta V$	Input Edge Rate, V _{IN} = 0.8V–2.0V, V _{CC} = 3.0V		0	10	ns/V

Note 4: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 5: I_O Absolute Maximum Rating must be observed.

Note 6: Unused inputs or I/O's must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	Conditions	v _{cc}	$T_A = -40^{\circ}C$	to +85°C	Units
Symbol	Faranieter	Conditions	(V)	Min	Max	onits
V _{IH}	HIGH Level Input Voltage		2.3 - 2.7	1.7		V
			2.7 - 3.6	2.0		v
V _{IL}	LOW Level Input Voltage		2.3 - 2.7		0.7	V
			2.7 - 3.6		0.8	v
V _{OH}	HIGH Level Output Voltage	I _{OH} = -100 μA	2.3 - 3.6	V _{CC} - 0.2		
		I _{OH} = -8 mA	2.3	1.8		
		I _{OH} = -12 mA	2.7	2.2		V
		I _{OH} = -18 mA	3.0	2.4		
		I _{OH} = -24 mA	3.0	2.2		
V _{OL}	LOW Level Output Voltage	I _{OL} = 100 μA	2.3 - 3.6		0.2	
		$I_{OL} = 8mA$	2.3		0.6	
		I _{OL} = 12 mA	2.7		0.4	V
		I _{OL} = 16 mA	3.0		0.4	
		I _{OL} = 24 mA	3.0		0.55	
1	Input Leakage Current	$0 \le V_I \le 5.5V$	2.3 - 3.6		±5.0	μA
oz	3-STATE I/O Leakage	$0 \le V_O \le 5.5V$	2.3 - 3.6		±5.0	
		$V_I = V_{IH} \text{ or } V_{IL}$				μA
OFF	Power-Off Leakage Current	$V_1 \text{ or } V_0 = 5.5 V$	0		10	μA

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DC Electrical Characteristics (Continued)

	Symbol	Parameter	Conditions V_{CC} $T_A = -40^{\circ}$		$V_{CC} = -40^{\circ}C \text{ to } +85$		C to ⊹85°C	Units
í	Gymbol	r arameter	Conditiona	(V)	Min	Max	Onito	
	I _{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.3–3.6		20	μA	
			$3.6V \leq V_{I}, V_{O} \leq 5.5V$ (Note 7)	2.3–3.6		±20	μι	
Ľ	ΔI_{CC}	Increase in I _{CC} per Input	$V_{IH} = V_{CC} - 0.6V$	2.3–3.6		500	μΑ	

Note 7: Outputs disabled or 3-STATE only.

AC Electrical Characteristics

		$\mathbf{T}_{\mathbf{A}} = -40^{\circ}\mathbf{C} \text{ to } +85^{\circ}\mathbf{C}, \ \mathbf{R}_{\mathbf{L}} = 500 \Omega$						
Symbol	Barrantan	V _{CC} = 3.	$3V \pm 0.3V$	V _{CC} =	2.7V	V _{CC} = 2.	$5V \pm 0.2V$	
	Parameter	C _L = 50 pF		C _L = 50 pF		C _L = 30 pF		Units
		Min	Max	Min	Max	Min	Max	-
t _{PHL}	Propagation Delay	1.5	4.5	1.5	5.2	1.5	5.4	
t _{PLH}	A _n to B _n or B _n to A _n	1.5	4.5	1.5	5.2	1.5	5.4	ns
t _{PZL}	Output Enable Time	1.5	6.5	1.5	7.2	1.5	8.5	
t _{PZH}		1.5	6.5	1.5	7.2	1.5	8.5	ns
t _{PLZ}	Output Disable Time	1.5	6.4	1.5	6.9	1.5	7.7	
t _{PHZ}		1.5	6.4	1.5	6.9	1.5	7.7	ns
t _{OSHL}	Output to Output Skew		1.0					
t _{OSLH}	(Note 8)		1.0					ns

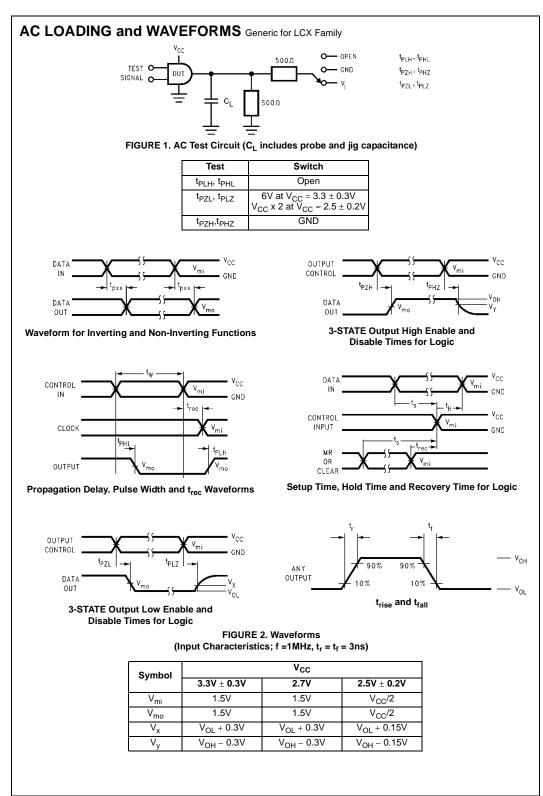
Note 8: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}). Parameter guaranteed by design.

Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V _{cc}	$T_A = 25^{\circ}C$	Units
	Falameter	conditions	(V)	Typical	Units
V _{OLP}	Quiet Output Dynamic Peak V _{OL}	$C_L = 50 \text{ pF}, \text{ V}_{IH} = 3.3 \text{ V}, \text{ V}_{IL} = 0 \text{ V}$	3.3	0.8	V
		$C_L = 30 \text{ pF}, \text{ V}_{IH} = 2.5 \text{V}, \text{ V}_{IL} = 0 \text{V}$	2.5	0.6	v
V _{OLV}	Quiet Output Dynamic Valley V _{OL}	$C_{L} = 50 \text{ pF}, \text{ V}_{IH} = 3.3 \text{ V}, \text{ V}_{IL} = 0 \text{ V}$	3.3	-0.8	V
		$C_L = 30 \text{ pF}, \text{ V}_{IH} = 2.5 \text{V}, \text{ V}_{IL} = 0 \text{V}$	2.5	-0.6	v

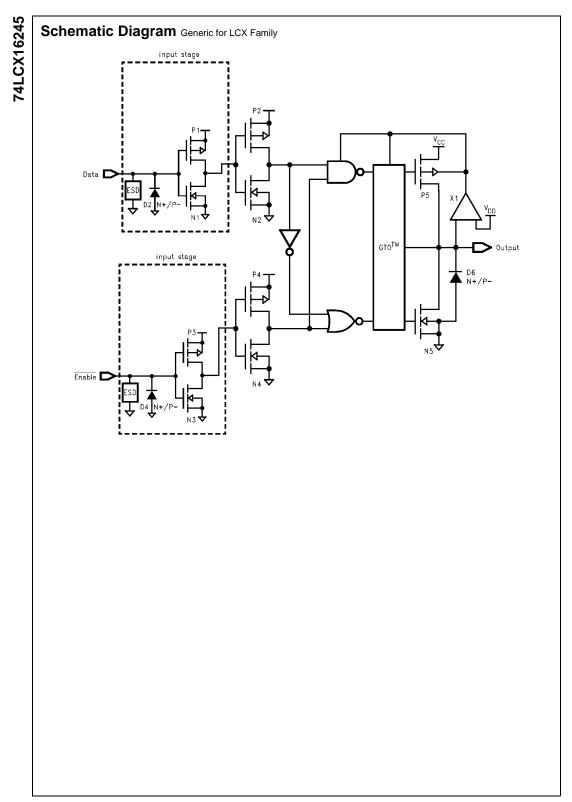
Capacitance

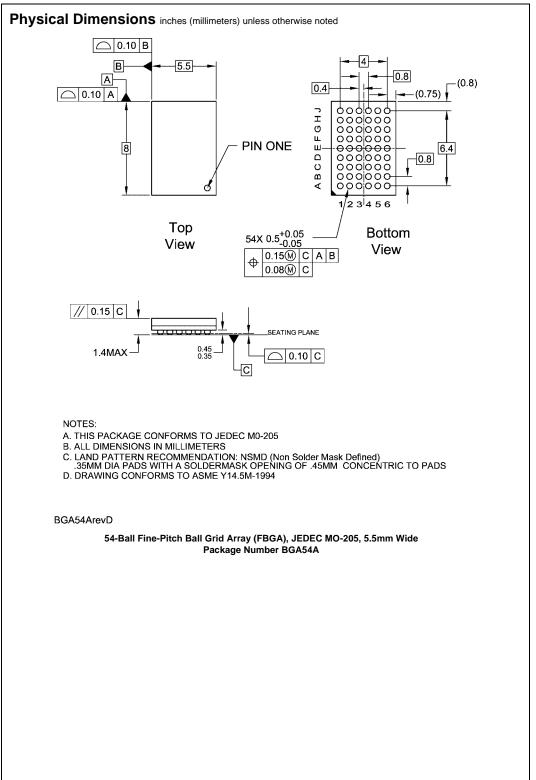
Symbol	Parameter	Conditions	Typical	Units
CIN	Input Capacitance	$V_{CC} = Open, V_I = 0V \text{ or } V_{CC}$	7	pF
C _{I/O}	Input/Output Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}	8	pF
C _{PD}	Power Dissipation Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC} , f = 10 MHz	20	pF

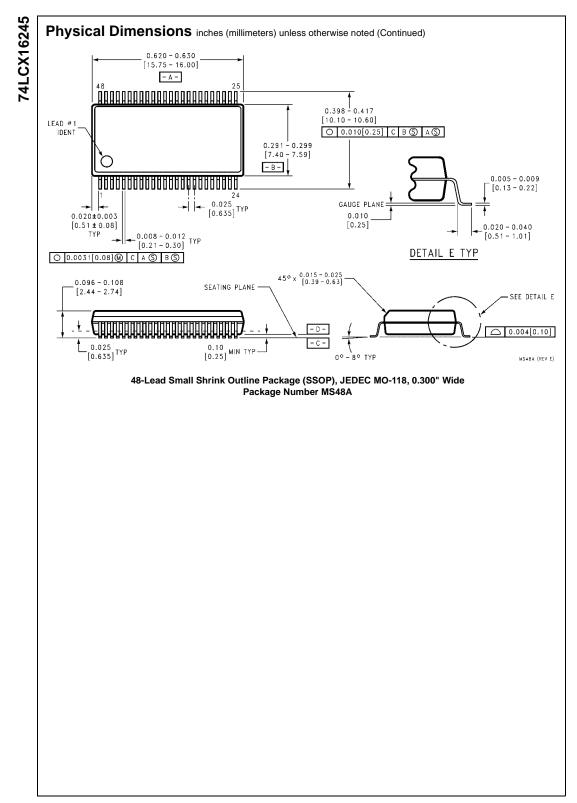


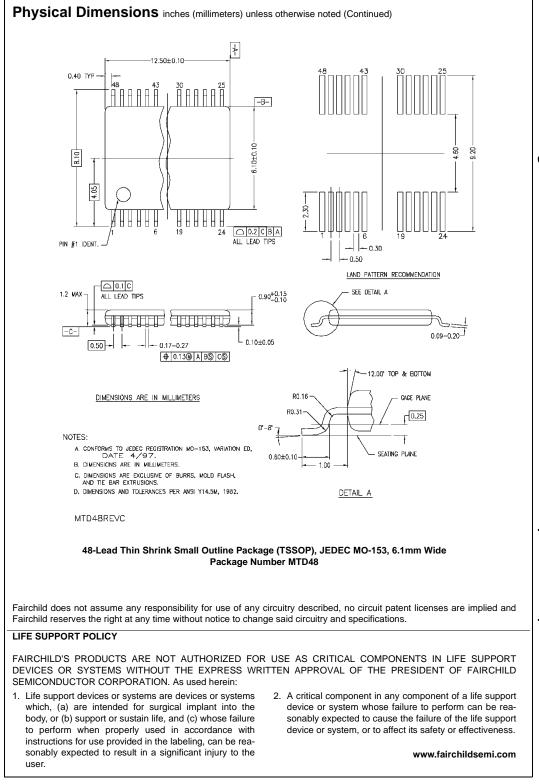
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